

长春新产业光电技术有限公司

Changchun New Industries Optoelectronics Tech. Co., Ltd.

DATA SHEET

MLL-H-1064/2000~3000mW

SPECIFICATIONS

LOW NOISE INFRARED LASER AT 1064 nm

All solid state low noise infrared laser at 1064 nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in scientific experiment, optical instrument, optical sensor, measurement, communication, spectrum analysis, etc.



Wavelength (nm)	1064 ± 1	
Operating mode	CW	
Output power (mW)	>2000, 2100, 2200, ,3000	
Power stability (rms, over 4 hours)	<1%, <2%, <3%	
Transverse mode	Near TEM ₀₀	
Noise of amplitude(rms, 20Hz~20MHz)	<1%	
Warm-up time (minutes)	<10	
M ² factor	<2.0	
Beam divergence, full angle (mrad)	<2.0	
Beam diameter at the aperture (mm)	~3.0	
Beam height from base plate (mm)	29	
Polarization ratio	>100:1	
Pointing stability after warm-up (mrad)	<0.05	
Operating temperature (°C)	10~35	
Power supply (90-264VAC)	PSU-H-FDA/PSU-H-OEM	
Expected lifetime (hours)	10000	
Warranty period	1 year	





nis device complies with 21 CFR1040.10 and 1040.11 angehun New Industries Optoelectronics Tech. Co., Ltd. (CNI) 58 JinHu Road High-tech Zone Changehun, China

